# Old Company Name in Catalogs and Other Documents

On April 1<sup>st</sup>, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: <a href="http://www.renesas.com">http://www.renesas.com</a>

April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<a href="http://www.renesas.com">http://www.renesas.com</a>)

EOL announ

Send any inquiries to <a href="http://www.renesas.com/inquiry">http://www.renesas.com/inquiry</a>.



### Notice

- 1. All information included in this document is current as of the date this document is issued. Such information, however, is subject to change without any prior notice. Before purchasing or using any Renesas Electronics products listed herein, please confirm the latest product information with a Renesas Electronics sales office. Also, please pay regular and careful attention to additional and different information to be disclosed by Renesas Electronics such as that disclosed through our website.
- 2. Renesas Electronics does not assume any liability for infringement of patents, copyrights, or other intellectual property rights of third parties by or arising from the use of Renesas Electronics products or technical information described in this document. No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights of Renesas Electronics or others.
- 3. You should not alter, modify, copy, or otherwise misappropriate any Renesas Electronics product, whether in whole or in part.
- 4. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation of these circuits, software, and information in the design of your equipment. Renesas Electronics assumes no responsibility for any losses incurred by you or third parties arising from the use of these circuits, software, or information.
- 5. When exporting the products or technology described in this document, you should comply with the applicable export control laws and regulations and follow the procedures required by such laws and regulations. You should not use Renesas Electronics products or the technology described in this document for any purpose relating to military applications or use by the military, including but not limited to the development of weapons of mass destruction. Renesas Electronics products and technology may not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations.
- 6. Renesas Electronics has used reasonable care in preparing the information included in this document, but Renesas Electronics does not warrant that such information is error free. Renesas Electronics assumes no liability whatsoever for any damages incurred by you resulting from errors in or omissions from the information included herein.
- 7. Renesas Electronics products are classified according to the following three quality grades: "Standard", "High Quality", and "Specific". The recommended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below. You must check the quality grade of each Renesas Electronics product before using it in a particular application. You may not use any Renesas Electronics product for any application categorized as "Specific" without the prior written consent of Renesas Electronics. Further, you may not use any Renesas Electronics product for any application for which it is not intended without the prior written consent of Renesas Electronics. Renesas Electronics shall not be in any way liable for any damages or losses incurred by you or third parties arising from the use of any Renesas Electronics product for an application categorized as "Specific" or for which the product is not intended where you have failed to obtain the prior written consent of Renesas Electronics. The quality grade of each Renesas Electronics product is "Standard" unless otherwise expressly specified in a Renesas Electronics data sheets or data books, etc.
  - "Standard": Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; and industrial robots.
  - "High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control systems; anti-disaster systems; anti-crime systems; safety equipment; and medical equipment not specifically designed for life support.
  - "Specific": Aircraft; aerospace equipment; submersible repeaters; nuclear reactor control systems; medical equipment or systems for life support (e.g. artificial life support devices or systems), surgical implantations, or healthcare intervention (e.g. excision, etc.), and any other applications or purposes that pose a direct threat to human life.
- 8. You should use the Renesas Electronics products described in this document within the range specified by Renesas Electronics, especially with respect to the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. Renesas Electronics shall have no liability for malfunctions or damages arising out of the use of Renesas Electronics products beyond such specified ranges.
- 9. Although Renesas Electronics endeavors to improve the quality and reliability of its products, semiconductor products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Further, Renesas Electronics products are not subject to radiation resistance design. Please be sure to implement safety measures to guard them against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a Renesas Electronics product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the final products or system manufactured by you.
- 10. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. Please use Renesas Electronics products in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. Renesas Electronics assumes no liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
- 11. This document may not be reproduced or duplicated, in any form, in whole or in part, without prior written consent of Renesas Electronics
- 12. Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products, or if you have any other inquiries.
- (Note 1) "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its majority-owned subsidiaries.
- (Note 2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.



# M66311P/FP

# 16-Bit LED Driver with Shift Register and Latch

REJ03F0177-0201 Rev.2.01 Mar 31, 2008

## **Description**

M66311P/FP is a LED array driver having a 16 bit serial-input and parallel output shiftregister function with direct coupled reset input and output latch function.

This product guarantees the output electric current of 24 mA which is sufficient for anode common LED drive, capable of flowing 16 bits continuously at the same time.

Parallel output is open drain output.

In addition, as this product has been designed in complete CMOS, power consumption can be greatly reduced when compared with conventional BIPOLAR or Bi-CMOS products.

Furthermore, pin lay-out ensures the realization of an easy printed circuit.

### **Features**

- Anode common LED drive
- High output current all parallel output  $I_{OL} = 24$  mA simultaneous lighting available
- Low power dissipation: 100 µW/package (max)
  - $(V_{CC} = 5 \text{ V}, \text{ Ta} = 25^{\circ}\text{C}, \text{ quiescent state})$
- High noise margin
  - schmitt input circuit provides responsiveness to a long line length.
- Equipped with direct-coupled reset
- Open drain output
  - (except serial data output)
- Wide operating temperature range:  $Ta = -40 \text{ to } +85^{\circ}\text{C}$
- Pin lay-out facilitates printed circuit wiring. (This lay-out facilitates cascade connection and LED connection.)

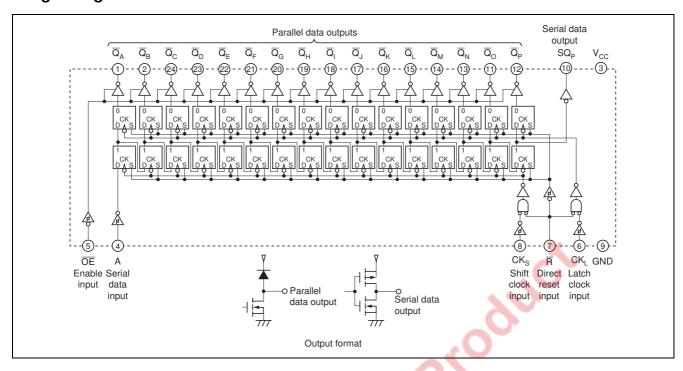
## **Application**

LED array drive of BUTTON TELEPHONE

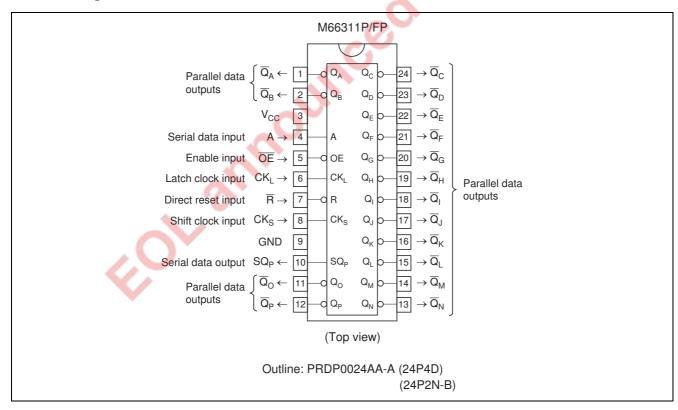
LED array drive of ERASER of a PPC copier

Other various LED modules

## **Logic Diagram**



## **Pin Arrangement**



## **Functional Description**

As M66311P/FP uses silicon gate CMOS process, it realizes high-speed and high-output currents sufficient for LED drive while maintaining low power consumption and allowance for high noises.

Each bit of a shiftregister consists of two flip-flops having independent clocks for shifting and latching.

As for clock input, shift clock input  $CK_S$  and latch clock input  $CK_L$  are independent from each other, shift and latch operations being made when "L" changes to "H".

Serial data input A is the data input of the first–step shiftregister and the signal of A shifts shifting registers one by one when a pulse is impressed to CK<sub>S</sub>. When A is "H", the signal of "L" shifts.

When the pulse is impressed to  $CK_L$ , the contents of the shifting register at that time are stored in a latching register, and they appear in the outputs from  $\overline{Q}_A$  to  $\overline{Q}_P$ .

Outputs from  $\overline{Q}_A$  to  $\overline{Q}_P$  are open drain outputs.

To extend the number of bits, use the serial data output SQ<sub>P</sub> which shows the output of the shifting register of the 16th bit.

If  $CK_S$  and  $CK_L$  are connected, the state of the shifting register with one clock delay is outputted to  $\overline{Q}_A$  to  $\overline{Q}_P$ .

When reset input  $\overline{R}$  is changed to "L",  $\overline{Q}_A$  to  $\overline{Q}_P$  and  $SQ_P$  are reset. In this case, shifting and latching registers are set.

If "H" is impressed to output enable input OE,  $\overline{Q}_A$  to  $\overline{Q}_P$  reaches the high impedance state, but  $SQ_P$  does not reach the high impedance state. Furthermore, change in OE does not affect shift operation.

## Function Table (Note)

		Input					Parallel Data Output							Serial Data Output										
Operation	Mode	R	CKs	CKL	Α	ŌĒ	$\overline{Q}_{\overline{A}}$	$\overline{Q}_{\overline{B}}$	$\overline{Q}_{\overline{C}}$	$\overline{Q}_{\overline{D}}$	$\overline{Q}_{\overline{E}}$	$\overline{Q}_{\overline{F}}$	$\overline{Q}_{\overline{G}}$	$\overline{Q}_{\overline{H}}$	$\overline{Q}_{\overline{l}}$	$\overline{Q}_{\overline{J}}$	$\overline{Q}_{\overline{K}}$	$\overline{Q}_{\overline{L}}$	$\overline{Q}_{\overline{M}}$	$\overline{Q}_{\overline{N}}$	$\overline{Q}_{\overline{O}}$	$\overline{Q}_{\overline{P}}$	SQ <sub>P</sub>	Remarks
Reset		L	Χ	Х	Χ	Χ	Z	Z	Z	Z	Z	Z	Z	Z	Z	Z	Z	Z	Z	Z	Z	Z	L	-
Shift	Shift t1	Н	1	Х	Н	L	$\overline{Q}_{\overline{A}}^0$	$\overline{Q}_{\overline{B}}^0$	$\overline{Q}_{\overline{C}^0}$	$\overline{Q}_{\overline{D}}^0$	$\overline{Q}_{\overline{E}^0}$	$\overline{Q}_{\overline{F}}^0$	$\overline{Q}_{\overline{G}}^{0}$	$\overline{Q}_{\overline{H}^0}$	$\overline{Q}_{\overline{l}}^0$	$\overline{Q}_{\overline{J}^0}$	$\overline{Q}_{\overline{K}}^0$	$\overline{Q}_{\overline{L}^0}$	$\overline{Q}_{\overline{M}}^{0}$	$\overline{Q}_{\overline{N}}^{0}$	$\overline{Q}_{\overline{O}}^0$	$\overline{Q}_{\overline{P}^0}$	$q_0^0$	Output
latch	Latch t2	Н	Х	1	Х	L	L	$q_A^0$	q <sub>B</sub> <sup>0</sup>	q <sub>C</sub> <sup>0</sup>	$q_D^0$	q <sub>E</sub> <sup>0</sup>	q <sub>F</sub> <sup>0</sup>	$q_G^0$	q <sub>H</sub> <sup>0</sup>	q <sub>I</sub> <sup>0</sup>	q <sub>J</sub> <sup>0</sup>	q <sub>K</sub> <sup>0</sup>	$q_L^0$	q <sub>M</sub> <sup>0</sup>	q <sub>N</sub> <sup>0</sup>	q <sub>o</sub> <sup>0</sup>	$q_0^0$	lighting "H"
operation	Shift t1	Н	1	Х	L	L	$\overline{Q}_{\overline{A}}^0$	$\overline{Q}_{\overline{B}}^0$	$\overline{Q}_{\overline{C}^0}$	$\overline{Q}_{\overline{D}}^0$	$\overline{Q}_{\overline{E}}^{0}$	$\overline{Q}_{F}^{0}$	$\overline{Q}_{\overline{G}^0}$	$\overline{Q}_{\overline{H}^0}$	$\overline{Q}_{\overline{l}}^0$	$\overline{Q}_{\overline{J}^0}$	$\overline{Q}_{\overline{K}}^0$	$\overline{Q}_{\overline{L}^0}$	$\overline{Q}_{\overline{M}}^{0}$	$\overline{Q}_{\overline{N}}^{0}$	$\overline{Q}_{\overline{O}}^0$	$\overline{Q}_{\overline{P}^0}$	$q_0^0$	Output
	Latch t2	Н	Х	<b>↑</b>	Х	L	Z	$q_A^0$	q <sub>B</sub> <sup>0</sup>	q <sub>C</sub> <sup>0</sup>	$q_D^0$	q <sub>E</sub> 0	q <sub>F</sub> 0	$q_G^0$	q <sub>H</sub> <sup>0</sup>	q <sub>I</sub> <sup>0</sup>	q <sub>J</sub> <sup>0</sup>	q <sub>K</sub> <sup>0</sup>	$q_L^0$	q <sub>M</sub> <sup>0</sup>	q <sub>N</sub> <sup>0</sup>	q <sub>O</sub> <sup>0</sup>	$q_0^0$	lights-out "L"
Output dis	able	Х	Х	Х	Х	Н	Z	Z	Z	Z	Z	Z	Z	Z	Z	Z	Z	Z	Z	Z	Z	Z	$q_P$	_

Note 1: Change from low-level to high-level

Q

Output state Q before CK<sub>L</sub> changed

X: Irrelevant

q0: Contents of shift register before CKs changed

q: Contents of shift register

t<sub>1</sub>, t<sub>2</sub>: t<sub>2</sub> is set after t<sub>1</sub> is set

Z: High impedance

# **Absolute Maximum Ratings**

 $(Ta = -40 \text{ to } +85^{\circ}\text{C}, \text{ unless otherwise noted})$ 

Item	Symbol	Ratings	Unit	Conditions							
Supply voltage	V <sub>CC</sub>	−0.5 to +7.0	٧								
Input voltage		Vı	$-0.5$ to $V_{CC} + 0.5$	٧							
Output voltage	voltage		·oltage		it voltage		ut voltage		$-0.5$ to $V_{CC} + 0.5$	٧	
Input protection diode current	I <sub>IK</sub>	-20	mA	$V_I < 0 V$							
		20		$V_{\text{I}} > V_{\text{CC}}$							
Output parasitic diode current	le current		-20	mA	V <sub>O</sub> < 0 V						
					$V_{\text{O}} > V_{\text{CC}}$						
Output current per output pin	$\overline{Q}_A$ to $\overline{Q}_P$	lo	50	mA							
	SQ <sub>P</sub>		±25								
Supply/GND current	Icc	-20, +410	mA	V <sub>CC</sub> , GND							
Power dissipation	Pd	500	mW	(Note)							
Storage temperature range		Tstg	-65 to +150	°C	A						

Note: M66311FP; Ta = -40 to +70°C, Ta = 70 to 85°C are derated at -6 mW/°C.

# **Recommended Operating Conditions**

 $(Ta = -40 \text{ to } +85^{\circ}\text{C}, \text{ unless otherwise noted})$ 

		Limits					
Item	Symbol	Min	Тур	Max	Unit		
Supply voltage	V <sub>CC</sub>	4.5	5	5.5	V		
Input voltage	Vi	0	_	V <sub>CC</sub>	V		
Output voltage	Vo	0	_	V <sub>CC</sub>	V		
Operating temperature range	Topr	-40	_	+85	°C		

## **Electrical Characteristics**

 $(V_{CC} = 4.5 \text{ to } 5.5V, \text{ unless otherwise noted})$ 

	Sy			Limits						
mb Item ol		T	a = 25°	С	Ta = -40	to +85°C				
		Min	lin Typ Max		Min	Max	Unit	Conditions		
Positive-going threshold voltage	V <sub>T+</sub>	0.35×V <sub>CC</sub>	_	0.7×V <sub>CC</sub>	0.35×V <sub>CC</sub>	0.7×V <sub>CC</sub>	٧	$V_O = 0.1 \text{ V}, V_{CC}-0.1 \text{ V}$ $ I_O  = 20 \mu\text{A}$		
Negative-going threshold voltage	V <sub>T</sub>	0.2×V <sub>CC</sub>	_	0.55×V <sub>CC</sub>	0.2×V <sub>CC</sub>	0.55×V <sub>CC</sub>	٧	$V_{O} = 0.1 \text{ V}, V_{O}$ $ I_{O}  = 20  \mu\text{A}$	<sub>C</sub> -0.1 V	
Low-level	$V_{OL}$	1	_	0.1	_	0.1	V	$V_I=V_{T_+},\ V_{T-}$	$I_{OL} = 20 \mu A$	
output_voltage		_	_	0.44	_	0.53		$V_{CC} = 4.5 \text{ V}$	$I_{OL} = 24 \text{ mA}$	
$\overline{\mathbb{Q}}_{A}$ to $\overline{\mathbb{Q}}_{P}$		_	_	0.73	_	0.94		44	I <sub>OL</sub> = 40 mA	
High-level	V <sub>OH</sub>	V <sub>CC</sub> -0.1	_	_	V <sub>CC</sub> -0.1	_	V	$V_I = V_{T_+}, V_{T-}$	I <sub>OH</sub> = -20 μA	
output voltage SQ <sub>P</sub>		3.83	_	_	3.66			$V_{CC} = 4.5 \text{ V}$	$I_{OH} = -4 \text{ mA}$	
Low-level	$V_{OL}$	_	_	0.1	_	0.1	V	$V_I = V_{T_+}, \ V_{T-}$	$I_{OL} = 20 \mu A$	
output voltage SQ <sub>P</sub>		_	_	0.44	_	0.53	.0	V <sub>CC</sub> = 4.5 V	I <sub>OL</sub> = 4 mA	
High-level input current	I <sub>IH</sub>		_	0.5	_	5.0	μА	$V_I = V_{CC}, V_{CC} =$	= 5.5 V	
Low-level input current	I₁∟		_	-0.5	_	-5.0	μА	$V_I = GND, V_{CC}$	; = 5.5 V	
Maximum	lo	_	_	1.0	- /	10.0	μА	$V_I = V_{T+}, \ V_{T-}$	$V_O = V_{CC}$	
output leakage current $\overline{Q}_A$ to $\overline{Q}_P$		-	_	-1.0	70,	-10.0		$V_{CC} = 5.5 \text{ V}$	$V_O = GND$	
Quiescent supply current	Icc	_	_	20.0	<u> </u>	200.0	μА	$V_I = V_{CC}$ , GND	$V_{CC} = 5.5 V$	

Note: M66311 is used under the condition of an output current I<sub>OL</sub> = 40 mA, the number of simultaneous drive outputs is restricted as shown in the Duty Cycle-I<sub>OL</sub> of Standard characteristics.

# **Switching Characteristics**

 $(V_{CC} = 5 V)$ 

		Limits						
			Ta = 25°C		Ta = -40	to +85°C		
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions
Maximum clock frequency	f <sub>max</sub>	5	_	_	4		MHz	$C_L = 50 pF$
Low-level to high-level and	t <sub>PLH</sub>	_	_	100	_	130	ns	$R_L = 1 \text{ k}\Omega$ (Note 2)
high-level to low-level output propagation time (CK <sub>S</sub> -SQ <sub>P</sub> )	t <sub>PHL</sub>	_		100	_	130	ns	(Note 2)
$\begin{array}{c} \text{High-level to low-level} \\ \text{output propagation time } (\overline{R}\text{-}\\ \text{SQ}_{P}) \end{array}$	t <sub>PHL</sub>	_		100	_	130	ns	
Low-level to high-level output propagation time ( $\overline{R}$ - $\overline{Q}_A$ to $\overline{Q}_P$ )	t <sub>PLZ</sub>	_		150	_	200	ns	
Low-level to high-level and	t <sub>PZL</sub>	_	_	100	_	130	ns	
high-level to low-level output propagation time $(CK_L-\overline{Q}_A \text{ to } \overline{Q}_P)$	t <sub>PLZ</sub>	_	_	150	_	200	ns	
Output enable time to low-	t <sub>PZL</sub>	_		100	_	130	ns	
level and high-level ( $\overline{OE}$ – $\overline{Q}_A$ to $\overline{Q}_P$ )	t <sub>PLZ</sub>	_	l	150	0	200	ns	
Input Capacitance	Cı	_	_	10		10	pF	
Output Capacitance	Co	_		15	_	15	pF	$\overline{OE} = V_{CC}$
Power dissipation Capacitance (Note 1)	C <sub>PD</sub>	_	5	0	_	_	pF	

Note: 1. C<sub>PD</sub> is the internal capacitance of the IC calculated from operation supply current under no-load conditions. (per latch)

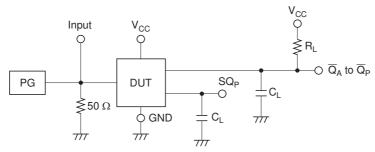
The power dissipated during operation under no-load conditions is calculated using the following formula:  $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_I + I_{CC} \bullet V_{CC}$ 

# **Timing Requirements**

 $(V_{CC} = 5 V)$ 

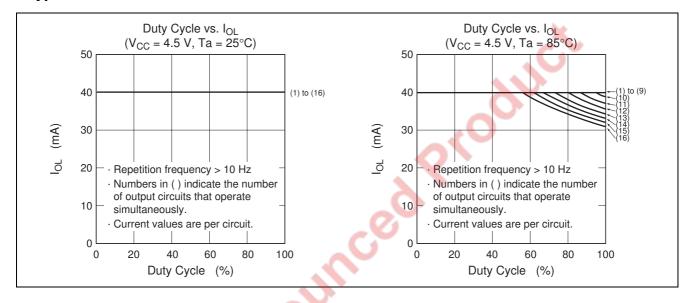
			Ta = 25°C		Ta = -40	to +85°C		
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions
CK <sub>S</sub> , CK <sub>L</sub> , R pulse width	t <sub>w</sub>	100	_	_	130	_	ns	(Note 2)
A setup time with respect to CK <sub>S</sub>	t <sub>su</sub>	100	_	_	130	_	ns	
CK <sub>S</sub> setup time with respect to CK <sub>L</sub>	t <sub>su</sub>	100	_	_	130		ns	
A hold time with respect to CK <sub>S</sub>	t <sub>h</sub>	10	_	_	15		ns	
R, recovery time with respect to CK <sub>S</sub> , CK <sub>L</sub>	t <sub>rec</sub>	50	_	_	70	_	ns	

Note: 2. Test Circuit

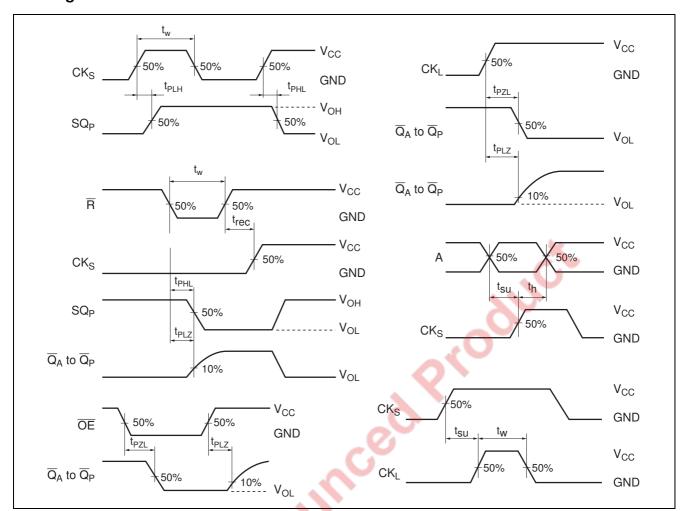


- (1) The pulse generator (PG) has the following characteristics (10% to 90%): tr = 6 ns, tf = 6 ns
- (2) The capacitance C<sub>L</sub> includes stray wiring capacitance and the probe input capacitance.

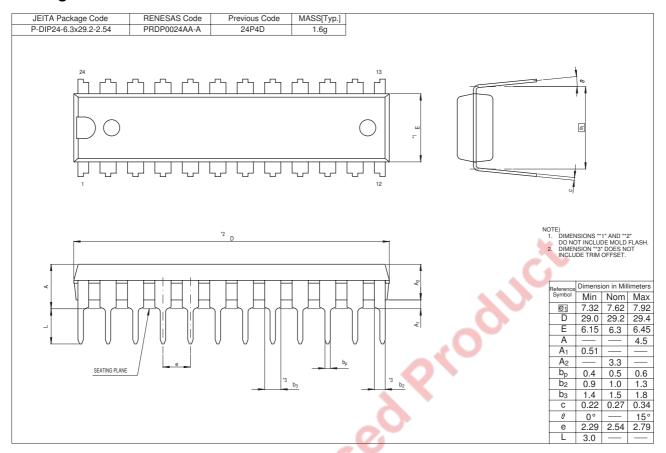
## **Typical Characteristics**



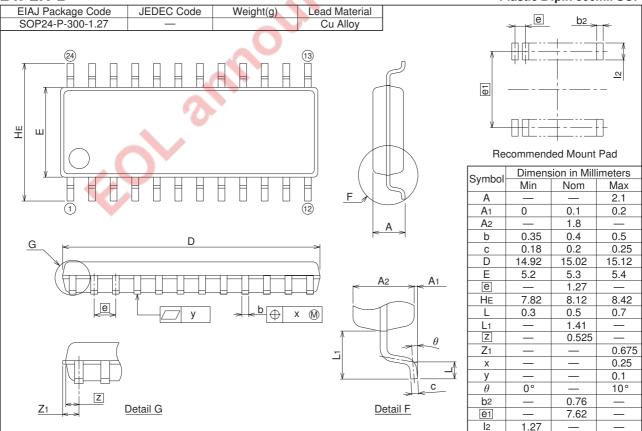
## **Timing Chart**



## **Package Dimensions**







Renesas Technology Corp. sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

- Renesas lechnology Corp. Sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Notes:

  1. This document is provided for reference purposes only so that Renesas customers may select the appropriate Renesas products for their use. Renesas neither makes warrantes or representations with respect to the accuracy or completeness of the information on this document nor grants any license to any intellectual property girbs to any other rights of representations with respect to the information in this document in this document of the purpose of the respect of the information in this document in the product data, diagrams, charts, programs, algorithms, and application critical examples.

  3. You should not use the products of the technology described in this document for the purpose of military use. When exporting the products or technology described herein, you should follow the applicable export control laws and regulations, and procedures required by such laws and regulations, and procedures required to the date this document in the such and the procedure of the proced



## **RENESAS SALES OFFICES**

http://www.renesas.com

Refer to "http://www.renesas.com/en/network" for the latest and detailed information.

### Renesas Technology America, Inc.

450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd.
Unit 204, 205, AZIACenter, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120 Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7858/7898

Renesas Technology Hong Kong Ltd.
7th Floor, North Tower, World Finance Centre, Harbour City, Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2377-3473

## Renesas Technology Taiwan Co., Ltd.

10th Floor, No.99, Fushing North Road, Taipei, Taiwar Tel: <886> (2) 2715-2888, Fax: <886> (2) 3518-3399

## Renesas Technology Singapore Pte. Ltd.

1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510